NSN 5962-01-220-9335

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View Online at https://aerobasegroup.com/nsn/5962-01-220-9335 **Body Length:** 1.290 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** 0.210 inches **Maximum Power Dissipation Rating:** 635.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** An/msq-t51 **Features Provided:** Hermetically sealed and burn in and ultraviolet erasable and monolithic and w/enable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 13 input **Case Outline Source And Designator:** D-3 mil-m-38510 **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 6.0 volts power source **Time Rating Per Chacteristic:** Err-060 hand pull and err-060 hand **Memory Device Type:** Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 printed circuit

Unit Of Measure:

N/a

Shelf Life:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0